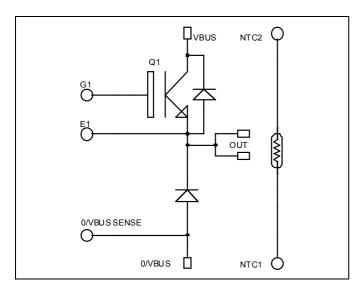
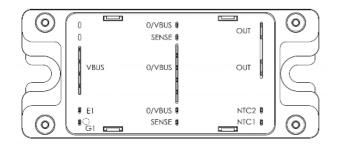


Buck chopper NPT IGBT Power Module





APTGF150SK120TG

$V_{CES} = 1200V$ $I_{C} = 150A$ @ Tc = 80°C

Application

- AC and DC motor control
- Switched Mode Power Supplies

Features

- Non Punch Through (NPT) Fast IGBT
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 50 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
 - Kelvin emitter for easy drive
- Very low stray inductance
 - Symmetrical design
 - Lead frames for power connections
- Internal thermistor for temperature monitoring
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Easy paralleling due to positive TC of VCEsat
- Low profile
- RoHS compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V _{CES}	Collector - Emitter Breakdown Voltage		1200	V
Т	I _C Continuous Collector Current		200	
IC	Continuous Conector Current	$T_c = 80^{\circ}C$	150	А
I _{CM}	Pulsed Collector Current	$T_c = 25^{\circ}C$	300	
V _{GE}	Gate – Emitter Voltage		±20	V
P _D	Maximum Power Dissipation	$T_c = 25^{\circ}C$	961	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 150^{\circ}C$	300A @ 1200V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
т	Zero Gate Voltage Collector Current				350	۸	
I _{CES}			$T_j = 125^{\circ}C$			600	μA
V	Collector Emitter saturation Voltage	$V_{GE} = 15V$	$T_j = 25^{\circ}C$		3.2	3.7	V
V _{CE(sat)}		$I_{\rm C} = 150 {\rm A}$ $T_{\rm j} = 125^{\circ} {\rm C}$	$T_{j} = 125^{\circ}C$		3.9		v
V _{GE(th)}	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 5 \text{ mA}$		4.5		6.5	V
I _{GES}	Gate – Emitter Leakage Current	$V_{GE} = \pm 20 V, V_{CE} = 0 V$				±500	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$		10.2		
C _{oes}	Output Capacitance	$V_{CE} = 25V$		1.4		nF
C _{res}	Reverse Transfer Capacitance	f = 1 MHz		0.75		
T _{d(on)}	Turn-on Delay Time	Inductive Switching (25°C)		120		
T _r	Rise Time	$V_{GE} = 15V$ $V_{GE} = 600V$		50		na
T _{d(off)}	Turn-off Delay Time	$V_{Bus} = 600V$ $I_{C} = 150A$		310		ns
$T_{\rm f}$	Fall Time	$R_G = 5.6\Omega$		20		
T _{d(on)}	Turn-on Delay Time	Inductive Switching (125°C)		130		
Tr	Rise Time	$V_{GE} = 15V$		60		
T _{d(off)}	Turn-off Delay Time	$V_{Bus} = 600V$ $I_C = 150A$ $R_G = 5.6\Omega$		360		ns
$T_{\rm f}$	Fall Time			30		
Eon	Turn-on Switching Energy	$\begin{array}{c} V_{GE} = 15V \\ V_{Bus} = 600V \end{array} T_{j} = 125^{\circ}C \end{array}$		18		mJ
E _{off}	Turn-off Switching Energy	$\begin{array}{c} I_{C} = 150A \\ R_{G} = 5.6\Omega \end{array} \qquad T_{j} = 125^{\circ}C \end{array}$		8		mJ

Chopper diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit	
V _{RRM}	Maximum Peak Repetitive Reverse Voltage			1200			V	
I _{RM}	Maximum Reverse Leakage Current	V _R =1200V	$T_j = 25^{\circ}C$			350	μA	
IRM	Maximum Reverse Leakage Current	VR 1200V	$T_{j} = 125^{\circ}C$			600	μΩ	
$I_{\rm F}$	DC Forward Current	$Tc = 70^{\circ}C$			200		А	
	Diode Forward Voltage	$I_{\rm F} = 200 {\rm A}$			2	2.5		
$V_{\rm F}$		$I_F = 400A$			2.3		V	
		$I_{\rm F} = 200 {\rm A}$	$T_{j} = 125^{\circ}C$		1.8			
+	Reverse Recovery Time		$T_j = 25^{\circ}C$		420		20	
t _{rr}	Reverse Recovery Time	$I_{\rm F} = 200 \text{A}$ $V_{\rm R} = 800 \text{V}$	$T_{j} = 125^{\circ}C$		520		ns	
Q _{rr}	Reverse Recovery Charge	$di/dt = 400 \text{A}/\mu\text{s}$	$T_j = 25^{\circ}C$		2.5		μC	
Qrr	Reverse Recovery charge				$T_{j} = 125^{\circ}C$		10.7	



APTGF150SK120TG

Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic	Min	Тур	Max	Unit
R ₂₅	Resistance @ 25°C		50		kΩ
B 25/85	$T_{25} = 298.15 \text{ K}$		3952		K
	D				

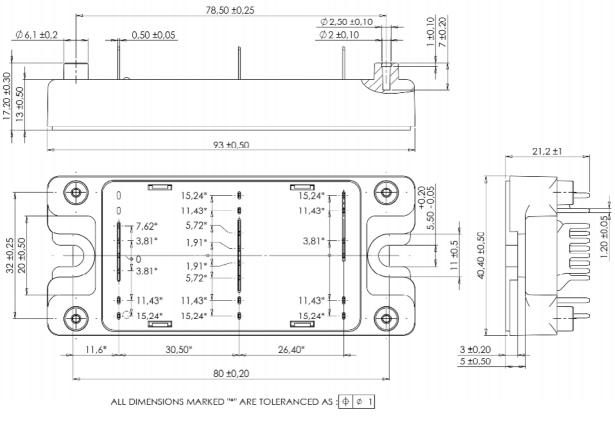
$$R_{T} = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]} R$$

 Γ : Thermistor temperature R_T : Thermistor value at T

Thermal and package characteristics

Symbol	Characteristic		Min	Тур	Max	Unit	
R _{thJC}	IC Junction to Case Thermal Resistance IGBT Diode				0.13	°C/W	
R _{th} JC			Diode			0.32	C/ W
VISOL	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T _J	Operating junction temperature range		-40		150		
T _{STG}	Storage Temperature Range Operating Case Temperature		-40		125	°C	
T _C			-40		100		
Torque	Mounting torque	To heatsink	M5	2.5		4.7	N.m
Wt	Package Weight					160	g

SP4 Package outline (dimensions in mm)

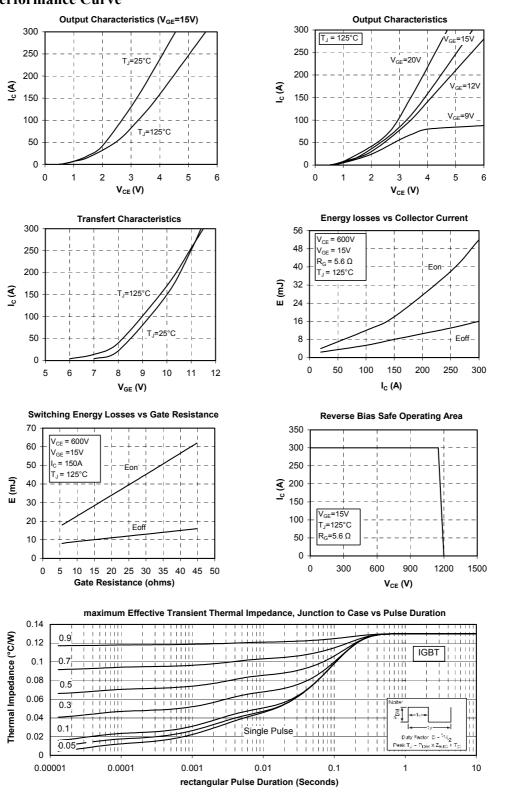


See application note APT0501 - Mounting Instructions for SP4 Power Modules on www.microsemi.com



Typical Performance Curve

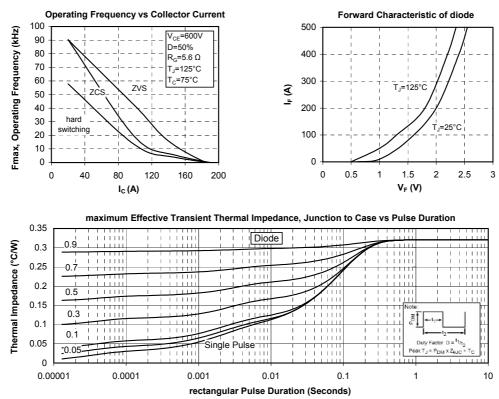




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APTGF150SK120TG

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